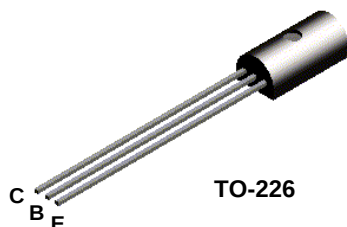


TN2219A



NPN General Purpose Amplifier

This device is for use as a medium power amplifier and switch requiring collector currents up to 500 mA. Sourced from Process 19. See PN2222A for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	75	V
V _{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector Current - Continuous	1.0	A
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		TN2219A	
P _D	Total Device Dissipation Derate above 25°C	1.0 8.0	W mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	125	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	50	°C/W

NPN General Purpose Amplifier

(continued)

TN2219A

Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
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OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}$, $I_B = 0$	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10 \text{ }\mu\text{A}$, $I_E = 0$	75		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \text{ }\mu\text{A}$, $I_C = 0$	6.0		V
I_{CEX}	Collector Cutoff Current	$V_{CE} = 60 \text{ V}$, $V_{EB(OFF)} = 3.0 \text{ V}$		10	nA
I_{CBO}	Collector Cutoff Current	$V_{CB} = 60 \text{ V}$, $I_E = 0$ $V_{CB} = 60 \text{ V}$, $I_E = 0$, $T_A = 150^\circ\text{C}$		10 10	nA μA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}$, $I_C = 0$		10	nA
I_{BL}	Base Cutoff Current	$V_{CE} = 60 \text{ V}$, $V_{EB(OFF)} = 3.0$		20	nA

ON CHARACTERISTICS

h_{FE}	DC Current Gain	$I_C = 0.1 \text{ mA}$, $V_{CE} = 10 \text{ V}$ $I_C = 1.0 \text{ mA}$, $V_{CE} = 10 \text{ V}$ $I_C = 10 \text{ mA}$, $V_{CE} = 10 \text{ V}$ $I_C = 150 \text{ mA}$, $V_{CE} = 10 \text{ V}$ $I_C = 150 \text{ mA}$, $V_{CE} = 1.0 \text{ V}$ $I_C = 500 \text{ mA}$, $V_{CE} = 10 \text{ V}$	35 50 75 100 50 40	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage*	$I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$		0.3 1.0	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage*	$I_C = 150 \text{ mA}$, $I_B = 1.0 \text{ mA}$ $I_C = 500 \text{ mA}$, $I_B = 5.0 \text{ mA}$	0.6	1.2 2.0	V V

SMALL SIGNAL CHARACTERISTICS

C_{obo}	Output Capacitance	$V_{CB} = 10 \text{ V}$, $I_E = 0$, $f = 100 \text{ kHz}$		8.0	pF
C_{ibo}	Input Capacitance	$V_{EB} = 0.5 \text{ V}$, $I_C = 0$, $f = 100 \text{ kHz}$		25	pF
h_{fe}	Small-Signal Current Gain	$I_C = 1.0 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $f = 1.0 \text{ kHz}$ $I_C = 10 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $f = 1.0 \text{ kHz}$	50 75	300 375	
$rb'C_C$	Collector Base Time Constant	$I_E = 20 \text{ mA}$, $V_{CB} = 20 \text{ V}$, $f = 31.8 \text{ MHz}$		150	pS
NF	Noise Figure	$I_C = 100 \text{ }\mu\text{A}$, $V_{CE} = 10 \text{ V}$, $R_S = 1.0 \text{ k}\Omega$, $f = 1.0 \text{ kHz}$, $B_W = 1.0 \text{ Hz}$		4.0	dB
$Re(h_{ie})$	Real Part of Common-Emitter High Frequency Input Impedance	$I_C = 20 \text{ mA}$, $V_{CE} = 20 \text{ V}$, $f = 300 \text{ MHz}$		60	Ω

SWITCHING CHARACTERISTICS

t_d	Delay Time	$V_{CC} = 30 \text{ V}$, $V_{BE(OFF)} = 0.5 \text{ V}$,		10	ns
t_r	Rise Time	$I_C = 150 \text{ mA}$, $I_{B1} = 15 \text{ mA}$		25	ns
t_s	Storage Time	$V_{CC} = 30 \text{ V}$, $I_C = 150 \text{ mA}$,		225	ns
t_f	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$		60	ns

*Pulse Test: Pulse Width $\leq 300 \text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$

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